

Hall Effect Sensor IC with Complementary Output Drivers and Frequency Generator

Features:

- Operate from 2.8V to 20V supply voltage.
- On-chip Hall sensor.
- Internal bandgap regulator allows temperature compensated operations and a wide operating voltage range.
- High output sinking capability up to 400mA for driving large load.
- Lower current change rate reduces the peak output voltages during switching.
- Available in rugged low profile SIP-4L/SIP-5L packages.
- Built-in protection diode for reverse power supply fault.

General Description:

WSH410 is designed to integrate Hall sensor with complementary output drivers and frequency generator together on the same chip, it is suitable for speed measurement, revolution counting, positioning, and DC brushless motors. It includes a temperature compensated voltage regulator, a differential amplifier, a Hysteresis controller, two open-collector output drivers capable of sinking 400mA current load. An on-chip protection diode is implemented to prevent reverse power fault.

The temperature-dependent bias increases the supply voltage of the hall plates and adjusts the switching points to the decreasing induction of magnets at higher temperatures. Subsequently, the open collector output switches to the appropriate state. WSH410 are rated for operation over temperature range from -20° C to125°C and voltage ranges from 2.8V to 20V.

| Name | P/I/O | Pin# | Description | |
|------|-------|------|-----------------------|--|
| Vcc | Р | 1 | Positive Power Supply | |
| OUT1 | 0 | 2 | Output Pin #1 | |
| OUT2 | 0 | 3 | Output Pin #2 | |
| Vss | Р | 4 | Ground | |

Pin Descriptions: SIP-4L



WSH410

Pin Descriptions: SIP-5L

| Name | P/I/O | Pin# | Description |
|------|-------|------|-----------------------|
| Vcc | Р | 1 | Positive Power Supply |
| OUT1 | 0 | 2 | Output Pin #1 |
| OUT2 | 0 | 3 | Output Pin #2 |
| FG | 0 | 4 | Frequency Generator |
| Vss | Р | 5 | Ground |

Absolute Maximum Rating (at Ta=25° C)

| Supply Voltage | | Vcc | | 20V | |
|-------------------------------|------------------|--------------|------|-------------------|-----------|
| Output / FG breakdown Voltage | | Vout | /Vfg | 25V | |
| | Magnetic flux de | ensity | В | | Unlimited |
| Reverse Protection Voltage | | Vr | | 20V | |
| | Output Current | continuous | Ic | | 300mA |
| | | Hold current | Ih | | 400mA |
| | | Peak current | Ip | | 800mA |
| FG ON Current (continuous) | | If | | 20mA | |
| Operating Temperature Range | | Ta | | (-20°C to +125°C) | |
| Storage Temperature Range | | Ts | | (-65°C to +150°C) | |
| Package Power Dissipation | | Pd | | 500mw for SIP-4L | |
| | | | | | |

SIP-5L

Electrical Characteristics: (T=+25°C, Vcc=2.8V to 20V)

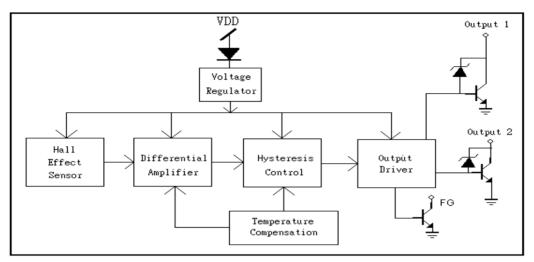
| Characteristic | Symbol | Test Conditions | Min | Тур | Max | Units |
|----------------------------------|-----------|------------------------------|-----|------|-----|-------|
| Supply Voltage | Vcc | | 2.8 | | 20 | V |
| Output Saturation Voltage | Vout(sat) | Vcc=20V, Ic=200mA B > Bop | | 0.2 | 0.4 | V |
| FG Saturation Voltage | Vfg(sat) | Vcc=20V, If=10mA B > Bop | | 0.15 | 0.4 | V |
| Output Leakage Current | Ileakage | Vcc=20V, B < Brp | | <0.1 | 10 | UA |
| Supply Current | Isupply | Vcc=20V, Output & FG Open | | 14 | 25 | MA |
| Output / FG Rising Time | Tr | Vcc=12V, RL=820Ω CL=20Pf | | 3.0 | 10 | Us |
| Output / FG Falling Time | Tf | Vcc=12V, RL=820Ω CL=20Pf | | 0.3 | 1.5 | Us |
| Output / FG Time Differential | ∆t | Vcc=12V, RL=820Ω CL=20Pf | | 0.3 | 3 | Us |

[©]Winson Semiconductor Corp. 2005/8/12 2





Function Block:



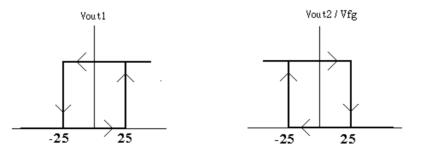
Magnetic Characteristics:

| | | | Ta= -2 | 20° C to + | -90°C | Unit |
|-------------------|---------|----------|--------|---------------------|-------|-------|
| Characteristics | Symbol | Quantity | Min | | Тур. | |
| | | | | Max | | |
| Operate Point | Bop | | | 70 | 120 | Gauss |
| Release Point | Brp | | -120 | -70 | | Gauss |
| Hysteresis Window | Bop-Brp | | | 40 | 200 | Gauss |

Ordering Information:

| SIP- 4L: WSH410-XPAN3 | (120 Guass) N:Non-lead Process |
|-----------------------|--------------------------------|
| SIP- 5L: WSH410-XPCN3 | (120 Guass) |

WSH410 Complementary Output1 vs.Output2/Vfg

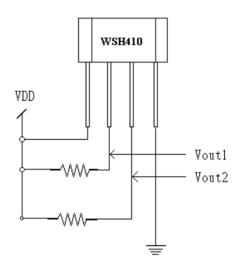


Magnetic Flux Density in Gauss

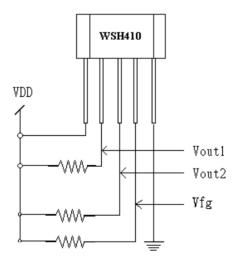


Test Circuit:

SIP-4L



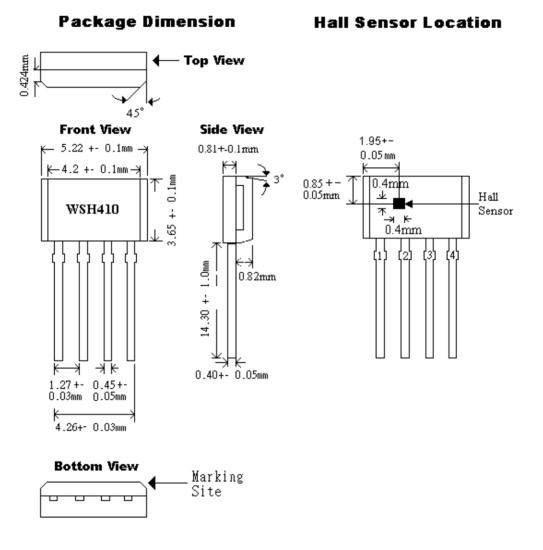
SIP-5L





Package Information:

SIP-4L

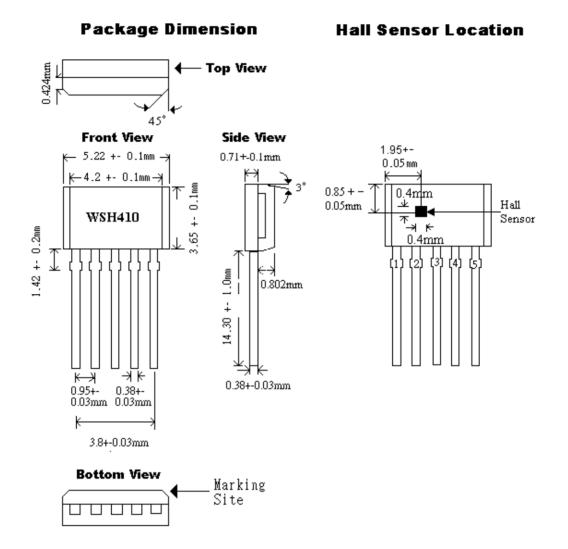


Winson reserves the right to make changes to improve reliability or manufacturability.

©Winson Semiconductor Corp. 2005/8/12 5



SIP-5L



Winson reserves the right to make changes to improve reliability or manufacturability.

©Winson Semiconductor Corp. 2005/8/12 6



Application Circuit:

SIP-4L

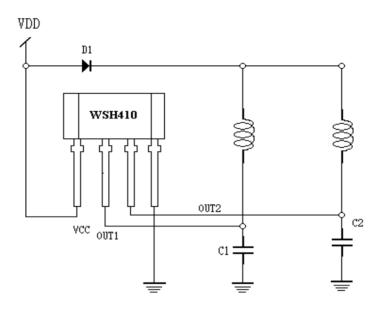


Figure 1.

SIP-5L

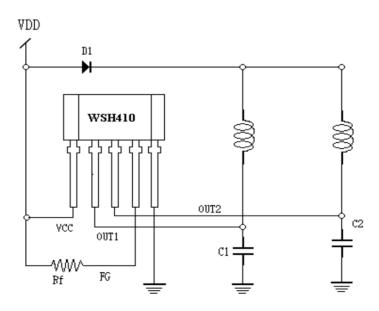


Figure 2. Winson reserves the right to make changes to improve reliability or manufacturability.

©Winson Semiconductor Corp. 2005/8/12 7